CATV 75 Ω pHEMT Dual RF Amplifier

TriQuint SEMICONDUCTOR

Applications

- V-ONU receiver output stage
- Multi-Dwelling Units
- Edge QAM
- Push-pull high-output stage
- SAT frequency distribution

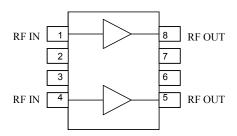


SOIC-8 package

Product Features

- 50-2600 MHz bandwidth
- pHEMT device technology
- Simple external tuning allows excellent return loss
- 5 V supply voltage
- 190 mA typical current consumption
- Easy bias current adjustment
- 13 dB typical gain
- 4.4 dB typical NF from 50 MHz to 1300 MHz
- Low distortion: CSO -83 dBc, CTB -75 dBc (33 dBmV/ch at output, 80 ch)
- SOIC-8 package

Functional Block Diagram



General Description

The TAT7464 is a 75 Ω RF Amplifier designed for use from 50 MHz to 2600 MHz, addressing the CATV and Satellite bands in a single part. The TAT7464 contains two separate amplifiers for push pull applications. It provides an easy means for adjusting bias current allowing designers to optimize power consumption for high efficiency applications. The TAT7464 is fabricated using 6-inch GaAs pHEMT technology to optimize performance and cost.

Pin Configuration

| Pin # | Symbol |
|--------------|------------|
| 1 | RF IN |
| 2, 3, 6, 7 | No Connect |
| 4 | RF IN |
| 5 | RF OUT |
| 8 | RF OUT |
| Exposed Slug | GND |

Ordering Information

| Part No. | Description |
|------------|---|
| TAT7464 | 75 Ω Dual pHEMT Amplifier (lead-free/RoHS compliant SOIC-8 Pkg) |
| TAT7464-EB | Amplifier Evaluation Board |

Standard T/R size = 1000 pieces on a 7" reel.



Specifications

Absolute Maximum Ratings¹

| Parameter | Rating |
|---|----------------|
| Storage Temperature | -65 to +150 °C |
| Device Voltage | +10 V |
| Thermal Resistance ² (jnt to case) θ_{ic} | 26 °C/W |

Notes:

- 1. Operation of this device outside the parameter ranges given above may cause permanent damage.
- 2. Refer to Thermal Analysis Report.

Recommended Operating Conditions

| Parameter | Min | Тур | Max | Units |
|---------------------------------------|-----|-----|-----|-------|
| $V_{ m DD}$ | | 5 | | V |
| I_{DD} | | 190 | | mA |
| $T_{\rm J}$ (for $> 10^6$ hours MTTF) | | | 145 | °C |

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions

Electrical Specifications

Test conditions unless otherwise noted: 25 °C, +5 V V_{DD}

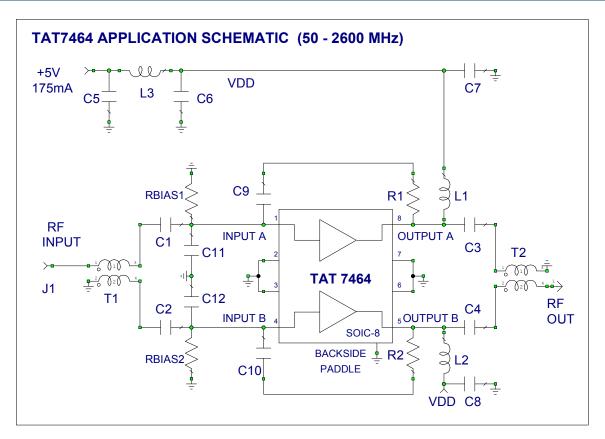
| Parameter | Conditions | Min | Typical | Max | Units |
|-----------------------------|-------------|-----|---------|------|-------|
| Operational Frequency Range | | 50 | | 2600 | MHz |
| Gain | | | 13 | | dB |
| Gain Flatness | See Note 5. | | +/- 0.5 | | dB |
| Noise Figure | See Note 1. | | 4.4 | | dB |
| Input Return Loss | | | 16 | | dB |
| Output Return Loss | | | 16 | | dB |
| CSO | See Note 2. | | -83 | | dBc |
| CTB | See Note 2. | | -75 | | dBc |
| Vsupply | | | +5 | | V |
| I_{DD} | | | 190 | | mA |

Notes:

- 1. 50 to 1300 MHz
- 2. 33 dBmV/ch at output, 80 ch flat
- 3. Electrical specifications are measured at specified test conditions.
- 4. Specifications are not guaranteed over all recommended operating conditions.
- 5. Gain flatness defined as the gain deviation from a best-fit straight line.



Application Circuit 50-2600 MHz



Notes:

1. See PC Board Layout, page 6 for more information.

Bill of Material

| Ref. Desg. | Value | Description | Manufacturer | Part Number |
|------------------------------------|---------|--|----------------------|------------------|
| U1 | | 75 Ω dual pHEMT Amplifier | TriQuint | TAT7464 |
| L1, L2, L3 | 500 nH | Chip Coil, Vertical Wire Wound Ferrite, 1206, 30 % | Murata | LQH31HNR50K |
| T1, T2 | | 1:1 balun ² | Mini-Circuits | TC1-1-13M-17+ |
| C1, C2, C5, C6, C7, C8, C9, C10 | 0.01 uF | Ceramic Chip Cap., 0402, 16 V, 10 %, X7R | AVX ¹ | 0402YC103KAT |
| C3, C4 | 150 pF | Ceramic Chip Cap., 0402, 50 V, 5 %, NPO | AVX ¹ | 04025C151JAT2A |
| C11, C12 | 0.7 pF | Ceramic Chip Cap., 0402, 50 V, +/- 0.1 pF | Yuden | UVK105CH0R7BW-F |
| R1, R2 | 680 Ω | Thick Film. Chip Res., 0402, 1/16 W, 1 %, | Dale ¹ | CRCW0402680RFKED |
| RBIAS1, RBIAS2 | no load | | | |
| J1, J2 | | SMB edge mount | Johnson ¹ | 131-8701-846 |

Notes:

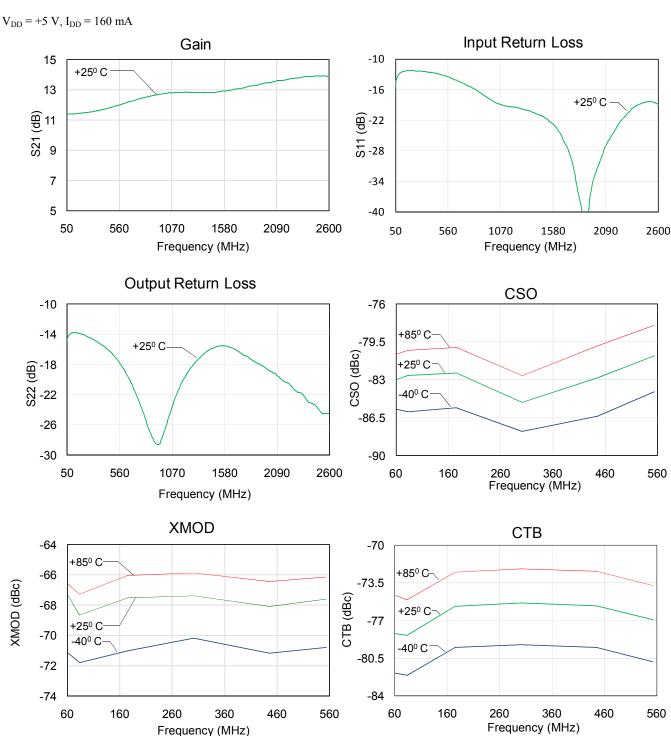
Preliminary Data Sheet: Rev D 06/24/10 © 2010 TriQuint Semiconductor, Inc.

^{1.} Or equivalent.

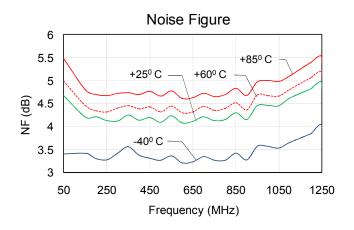
^{2. 1:1} balun may also be constructed using a binocular core (Fair Rite 2843002302; Type 43 material) with 1.5 turns of bifilar wire (MWS T2341222-10)



50-2600 MHz Application Board Typical Performance







Mechanical Information

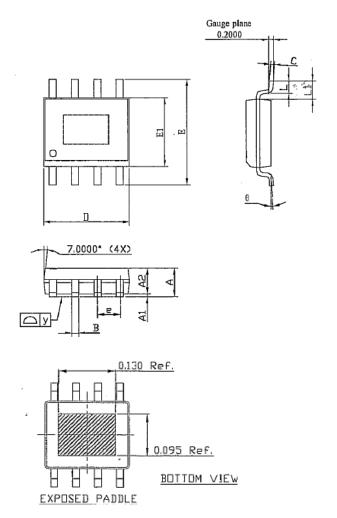
Package Information and Dimensions

This package is lead-free/RoHS-compliant. The plating material on the leads is 100% Matte Tin. It is compatible with both lead-free (maximum 260 °C reflow temperature) and lead (maximum 245 °C reflow temperature) soldering processes.

The TAT7464 will be marked with a "TAT7464" designator and an 8 digit alphanumeric lot code (XXXXYYWW). The first four digits are the lot code (XXXX). The last four digits are a date code consisting of the year and work week (YYWW) of assembly.

Dimensions in Inches

| symbol | Min. | nom. | Max. |
|-------------|-------|---------|-------|
| Α | 0.054 | 0.059 | 0.068 |
| A1 | (|) | 0.004 |
| A2 | | 0.057 | ' I |
| В | 0.013 | 3 | 0.020 |
| B C D | 0.007 | 7 | 0.010 |
| D | 0.189 | 9 | 0.197 |
| E1 | 0.150 | 0.153 | 0.157 |
| е | | 0.050 | 1 |
| E | 0.228 | 3 0.236 | 0.244 |
| L | 0.016 | 3 | 0.050 |
| У | l | | 0.004 |
| theta | (|) | 8 |
| L1 | 0.037 | 0.041 | 0.045 |



TAT7464

CATV 75 Ω pHEMT Dual RF Amplifier



Product Compliance Information

ESD Information



Caution! ESD-Sensitive Device

ESD Rating: Class 1 A+

Value: Passes ≥ 450 V min.

Test: Human Body Model (HBM)

Standard: JEDEC Standard JESD22-A114

ESD Rating: Class IIII+

Value: Passes $\geq 2000 \text{ V min.}$

Test: Charged Device Model (CDM)
Standard: JEDEC Standard JESD22-C101

MSL Rating

Level 3 at +260 °C convection reflow. The part is rated Moisture Sensitivity Level 3 at 260 °C per JEDEC standard IPC/JEDEC J-STD-020.

Solderability

Compatible with the latest version of J-STD-020, Lead free solder, 260 °C.

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

 Web:
 www.triquint.com
 Tel:
 +1.707.526.4498

 Email:
 info-sales@tqs.com
 Fax:
 +1.707.526.1485

For technical questions and application information:

Email: sicapplications.engineering@tgs.com

Important Notice

The information contained herein is believed to be reliable. TriQuint makes no warranties regarding the information contained herein. TriQuint assumes no responsibility or liability whatsoever for any of the information contained herein. TriQuint assumes no responsibility or liability whatsoever for the use of the information contained herein. The information contained herein is provided "AS IS, WHERE IS" and with all faults, and the entire risk associated with such information is entirely with the user. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for TriQuint products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information.

TriQuint products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.